TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74VCX157FT, TC74VCX157FK

Low Voltage Quad 2-Channel Multiplexer with 3.6 V Tolerant Inputs and Outputs

The TC74VCX157 is a high performance CMOS multiplexer which is guaranteed to operate from 1.2-V to 3.6-V. Designed for use in 1.5 V, 1.8 V, 2.5 V or 3.3 V systems, it achieves high. speed operation while maintaining the CMOS low power dissipation.

It is also designed with over voltage tolerant inputs and outputs up to 3.6 V.

It consists of four 2-input digital multiplexers with common select and strobe inputs.

When the \overline{ST} input is held "H" level, selection of data is inhibited and all the outputs become "L" level. The SELECT decoding determines whether the A or B inputs get routed to their corresponding Y outputs.

All inputs are equipped with protection circuits against static discharge.

Features

- Low voltage operation: $V_{CC} = 1.2 \sim 3.6 \text{ V}$
- High speed operation: $t_{pd} = 3.0 \text{ ns (max) (V}_{CC} = 3.0 \sim 3.6 \text{ V)}$

 $t_{pd} = 3.5 \text{ ns (max) (V}_{CC} = 2.3 \sim 2.7 \text{ V})$

 $t_{pd} = 7.0 \text{ ns (max) (VCC} = 1.65 \sim 1.95 \text{ V)}$

 $t_{pd} = 14.0 \text{ ns (max)} (V_{CC} = 1.68 \text{ 1.68 V})$

 $t_{pd} = 35.0 \text{ ns (max) (VCC} = 1.2 \text{ V)}$

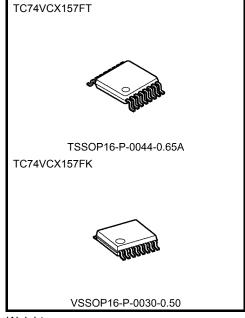
- 3.6 V tolerant inputs and outputs.
- Output current: $I_{OH}/I_{OL} = \pm 24 \text{ mA (min)} (V_{CC} = 3.0 \text{ V})$

 $I_{OH}/I_{OL} = \pm 18 \text{ mA (min) (V}_{CC} = 2.3 \text{ V)}$

 $I_{OH}/I_{OL} = \pm 6 \text{ mA (min)} (V_{CC} = 1.65 \text{ V})$

 $I_{OH}/I_{OL} = \pm 2 \text{ mA (min)} (V_{CC} = 1.4 \text{ V})$

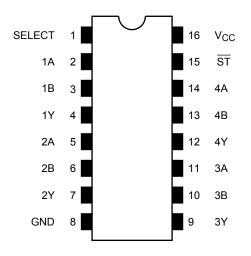
- Latch-up performance: -300 mA
- ESD performance: Machine model $\geq \pm 200 \text{ V}$ Human body model $\geq \pm 2000 \text{ V}$
- Package: TSSOP and VSSOP (US)
- Power down protection is provided on all inputs and outputs.



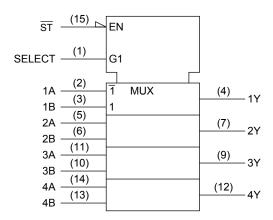
Weight

TSSOP16-P-0044-0.65A : 0.06 g (typ.) VSSOP16-P-0030-0.50 : 0.02 g (typ.)

Pin Assignment (top view)



IEC Logic Symbol

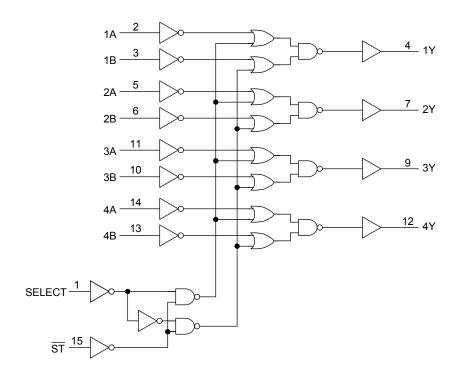


Truth Table

	Inputs							
ST	SELECT	Α	В	Υ				
Н	Х	X	X	L				
L	L	L	Х	L				
L	L	Н	X	Н				
L	Н	X	L	L				
L	Н	Х	Н	Н				

X: Don't care

System Diagram



Absolute Maximum Ratings (Note 1)

Characteristics	Symbol Rating		Unit	
Power supply voltage	V _{CC}	-0.5~4.6	V	
DC input voltage	V _{IN}	-0.5~4.6	V	
DC output voltage	Vout	-0.5~4.6 (Note 2)	V	
DC output voltage	VOU1	-0.5~V _{CC} + 0.5 (Note 3)		
Input diode current	I _{IK}	-50	mA	
Output diode current	I _{OK}	±50 (Note 4)	mA	
DC output current	lout	±50	mA	
Power dissipation	P _D	180	mW	
DC V _{CC} /ground current	I _{CC} /I _{GND}	±100	mA	
Storage temperature	T _{stg}	-65~150	°C	

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

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Note 2: $V_{CC} = 0 V$

Note 3: High or low state. IOUT absolute maximum rating must be observed.

Note 4: $V_{OUT} < GND, V_{OUT} > V_{CC}$



Operating Ranges (Note 1)

Characteristics	Characteristics Symbol Rating		Unit	
Supply voltage	V_{CC}	1.2~3.6	V	
Input voltage	V _{IN}	-0.3~3.6	V	
Output voltage	Vout	0~3.6 (Note 2)	V	
Output voltage	VOU1	0~V _{CC} (Note 3)	V	
		±24 (Note 4)		
Output ourrant	1/1	±18 (Note 5)		
Output current	I _{OH} /I _{OL}	±6 (Note 6)	mA	
		±2 (Note 7)		
Operating temperature	T _{opr}	-40~85	°C	
Input rise and fall time	dt/dv	0~10 (Note 8)	ns/V	

Note 1: The operating ranges must be maintained to ensure the normal operation of the device.

Unused inputs must be tied to either VCC or GND.

Note 2: $V_{CC} = 0 V$

Note 3: High or low state

Note 4: $V_{CC} = 3.0 \sim 3.6 \text{ V}$

Note 5: $V_{CC} = 2.3 \sim 2.7 \text{ V}$

Note 6: $V_{CC} = 1.65 \sim 1.95 \text{ V}$

Note 7: $V_{CC} = 1.4 \sim 1.6 \text{ V}$

Note 8: $V_{IN} = 0.8 \sim 2.0 \text{ V}, V_{CC} = 3.0 \text{ V}$

Electrical Characteristics

DC Characteristics (Ta = $-40\sim85^{\circ}$ C, 2.7 V < V_{CC} \leq 3.6 V)

Characteris	stics	Symbol Test Condition		V _{CC} (V)	Min	Max	Unit	
la marta de la ma	High level	V _{IH}		_	2.7~3.6	2.0	_	V
Input voltage	Low level	V _{IL}		_	2.7~3.6	_	0.8	V
				I _{OH} = -100 μA	2.7~3.6	V _{CC} - 0.2	_	
	High level	V _{OH}	V _{IN} = V _{IH} or V _{IL}	I _{OH} = -12 mA	2.7	2.2	_	
Output voltage				I _{OH} = -18 mA	3.0	2.4	_	V
				I _{OH} = -24 mA	3.0	2.2	_	
	Low level Vo		$V_{IN} = V_{IH}$ or V_{IL}	I _{OL} = 100 μA	2.7~3.6	_	0.2	
		V _{OL}		I _{OL} = 12 mA	2.7	_	0.4	
	LOW level			I _{OL} = 18 mA	3.0	_	0.4	
				I _{OL} = 24 mA	3.0	_	0.55	
Input leakage curre	nt	I _{IN}	V _{IN} = 0~3.6 V		2.7~3.6	_	±5.0	μΑ
Power off leakage of	wer off leakage current I _{OFF} V _{IN} , V _{OUT} = 0~3.6 V			0	_	10.0	μΑ	
Quiagaant aunnly aurrant		Icc	V _{IN} = V _{CC} or GND		2.7~3.6		20.0	
Quiescent supply co	Quiescent supply current		$V_{CC} \le V_{IN} \le 3.6 \text{ V}$		2.7~3.6		±20.0	μΑ
Increase in I _{CC} per	input	Δlcc	$V_{IH} = V_{CC} - 0.6 V$		2.7~3.6	_	750	

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DC Characteristics (Ta = $-40~85^{\circ}$ C, 2.3 V \leq V_{CC} \leq 2.7 V)

Characteris	stics	Symbol	Test	Test Condition		Min	Max	Unit
		Cymbol			V _{CC} (V)			5 1
Input voltage	High level	V _{IH}		_	2.3~2.7	1.6	_	V
input voltage	Low level	V _{IL}		_	2.3~2.7	_	0.7	V
High level			$I_{OH} = -100 \mu A$	2.3~2.7	V _{CC} - 0.2	_		
	High level	Voh	V _{IN} = V _{IH} or V _{II}	I _{OH} = -6 mA	2.3	2.0	_	v
				I _{OH} = -12 mA	2.3	1.8	_	
Output voltage				I _{OH} = -18 mA	2.3	1.7	_	
			$V_{IN} = V_{IH}$ or V_{IL}	$I_{OL} = 100 \mu A$	2.3~2.7	_	0.2	
	Low level	V _{OL}		I _{OL} = 12 mA	2.3	_	0.4	
				I _{OL} = 18 mA	2.3	_	0.6	
Input leakage current		I _{IN}	V _{IN} = 0~3.6 V		2.3~2.7	_	±5.0	μА
Power off leakage current I _{OFF}		l _{OFF}	V _{IN} , V _{OUT} = 0~3.6 V		0		10.0	μА
Quiasaant aunnly a	ırront	lcc	V _{IN} = V _{CC} or GND		2.3~2.7	_	20.0	μА
Quiescent supply cu	urent		$V_{CC} \le V_{IN} \le 3.6 \text{ V}$		2.3~2.7		±20.0	

DC Characteristics (Ta = $-40~85^{\circ}$ C, 1.65 V \leq V_{CC} < 2.3 V)

Characteris	Characteristics		Test (Condition	T	Min	Max	Unit
		Symbol	1001 00110111		V _{CC} (V)			5
Input voltage	High level	V _{IH}		_	1.65~2.3	0.65 × V _{CC}	_	V
input voltage	Low level	V _{IL}	_		1.65~2.3	_	0.2 × V _{CC}	V
High leve	High level	vel V _{OH}	$V_{IN} = V_{IH}$ or V_{IL}	I _{OH} = -100 μA	1.65~2.3	V _{CC} - 0.2		V
Output voltage				I _{OH} = -6 mA	1.65	1.25	_	
	Low level	James V	$V_{IN} = V_{IH}$ or V_{IL}	$I_{OL} = 100 \ \mu A$	1.65~2.3	_	0.2	
	Low level	V _{OL}		I _{OL} = 6 mA	1.65	_	0.3	
Input leakage currer	nt	I _{IN}	V _{IN} = 0~3.6 V		1.65~2.3	_	±5.0	μА
Power off leakage c	urrent	l _{OFF}	V _{IN} , V _{OUT} = 0~3.6 V		0	_	10.0	μА
Quiescent supply current		loo	V _{IN} = V _{CC} or GND		1.65~2.3	_	20.0	μА
		Icc	$V_{CC} \le V_{IN} \le 3.6 \text{ V}$		1.65~2.3	_	±20.0	μΑ



DC Characteristics (Ta = $-40~85^{\circ}$ C, 1.4 V \leq V_{CC} \leq 1.65 V)

Characteristics		Symbol	Test Condition		V _{CC} (V)	Min	Max	Unit
Input voltage	High level	V _{IH}	-	_		0.65 × V _{CC}	_	V
Input voltage	Low level	V _{IL}	_		1.4~1.65	_	0.05 × V _{CC}	V
High le	High level	level V _{OH}	$V_{IN} = V_{IH}$ or V_{IL}	I _{OH} = -100 μA	1.4~1.65	V _{CC} - 0.2	_	V
Output voltage				I _{OH} = -2 mA	1.4	1.05	_	
	Low level	Voi	V_{OL} $V_{IN} = V_{IH} \text{ or } V_{IL}$	$I_{OL} = 100 \mu A$	1.4~1.65		0.05	
	Low level	VOL		I _{OL} = 2 mA	1.4	_	0.35	
Input leakage curre	nt	I _{IN}	V _{IN} = 0~3.6 V	V _{IN} = 0~3.6 V		_	±5.0	μА
Power off leakage of	ower off leakage current I _{OFF} V _{IN} , V _{OUT} = 0~3.6 V			0	_	10.0	μА	
Quiescent supply cu	0.1		V _{IN} = V _{CC} or GND		1.4~1.65		20.0	^
Quiescent supply co	JI I CI I L	Icc	$V_{CC} \le V_{IN} \le 3.6 \text{ V}$		1.4~1.65	_	±20.0	μА

DC Characteristics (Ta = $-40\sim85^{\circ}$ C, 1.2 V \leq V_{CC} < 1.4 V)

Characteris			V _{CC} (V)	Min	Max	Unit		
	High level	V _{IH}	_		1.2~1.4	0.8 × V _{CC}	_	
Input voltage	Low level	V _{IL}	_		1.2~1.4	_	0.05 × V _{CC}	V
Output voltage	High level	VoH	V _{IN} = V _{IH} or V _{IL}	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $I_{OH} = -100 \mu\text{A}$		V _{CC} - 0.1	_	V
	Low level	V _{OL}	V _{IN} = V _{IH} or V _{IL}	I _{OL} = 100 μA	1.2	_	0.05	
Input leakage currer	nt	I _{IN}	V _{IN} = 0~3.6 V		1.2	_	±5.0	μΑ
Power off leakage of	urrent	loff	V _{IN} , V _{OUT} = 0~3.6 V		0	_	10.0	μΑ
Quiescent supply current		loo	$V_{IN} = V_{CC}$ or GND		1.2		20.0	μА
Quiescent supply cu	ITCIII	Icc	$V_{CC} \le V_{IN} \le 3.6 \text{ V}$		1.2	_	±20.0	μΑ

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AC Characteristics (Ta = $-40\sim85^{\circ}$ C, Input: $t_r = t_f = 2.0$ ns) (Note 1)

Characteristics	Symbol	Tes	Test Condition		Min	Max	Unit
0.1.01.01.01.01	- ,						
			$C_L = 15 pF, R_L = 2 k\Omega$	1.2	3.0	35.0	
Draw a gation, dalou time			OL - 13 β1 , IVL - 2 KΩ2	1.5 ± 0.1	2.0	14.0	
Propagation delay time (A, B-Y)	t _{pLH}	Figure 1, Figure 2		1.8 ± 0.15	1.5	7.0	ns
(A, D-1)	t _{pHL}		$C_L = 30 \text{ pF}, R_L = 500 \Omega$	2.5 ± 0.2	0.8	3.5	
				3.3 ± 0.3	0.6	3.0	
Propagation delay time (SELECT-Y)			$C_{I} = 15 pF, R_{I} = 2 k\Omega$	1.2	3.0	45.0	
	4		CL = 15 pr, RL = 2 KΩ	1.5 ± 0.1	2.0	18.0	ns
	t _{pLH}	Figure 1, Figure 2	$C_L = 30 \text{ pF}, R_L = 500 \Omega$	1.8 ± 0.15	1.5	9.0	
				2.5 ± 0.2	0.8	4.5	
				3.3 ± 0.3	0.6	3.5	
			$C_L = 15 \text{ pF}, R_L = 2 \text{ k}\Omega$	1.2	3.0	45.0	ns
Dronagation dolay time	.			1.5 ± 0.1	2.0	18.0	
Propagation delay time (ST -Y)	t _{pLH}	Figure 1, Figure 2		1.8 ± 0.15	1.5	9.0	
(31-1)	t _{pHL}		$C_L = 30 \text{ pF}, R_L = 500 \Omega$	2.5 ± 0.2	0.8	4.5	
				3.3 ± 0.3	0.6	3.5	
			$C_L = 15 pF, R_L = 2 k\Omega$	1.2		1.5	ns
Output to output skew	.		CL = 15 μι , NL = 2 KΩ	1.5 ± 0.1		1.5	
	t _{osLH} t _{osHL}	(Note 2)	$C_L=30$ pF, $R_L=500~\Omega$	1.8 ± 0.15		0.5	
				2.5 ± 0.2		0.5	
				3.3 ± 0.3	_	0.5	

Note 1: For $C_L = 50\ pF$, add approximately 300 ps to the AC maximum specification.

Note 2: This parameter is guaranteed by design. $(t_{OSLH} = |t_{DLHm} - t_{DLHn}|, t_{OSHL} = |t_{DHLm} - t_{DHLn}|)$



Dynamic Switching Characteristics (Ta = 25°C, Input: $t_r = t_f = 2.0$ ns, $C_L = 30$ pF)

Characteristics	Symbol	Test Condition	V _{CC} (V)	Тур.	Unit
		$V_{IH} = 1.8 \text{ V}, V_{IL} = 0 \text{ V}$ (Note) 1.8	0.25	
Quiet output maximum dynamic V _{OL}	V _{OLP}	$V_{IH} = 2.5 \text{ V}, V_{IL} = 0 \text{ V}$ (Note) 2.5	0.6	V
		$V_{IH} = 3.3 \text{ V}, V_{IL} = 0 \text{ V}$ (Note) 3.3	0.8	
	V _{OLV}	$V_{IH} = 1.8 \text{ V}, V_{IL} = 0 \text{ V}$ (Note	1.8	-0.25	
Quiet output minimum dynamic $V_{\mbox{OL}}$		$V_{IH} = 2.5 \text{ V}, V_{IL} = 0 \text{ V}$ (Note	2.5	-0.6	V
		$V_{IH} = 3.3 \text{ V}, V_{IL} = 0 \text{ V}$ (Note	3.3	-0.8	
		$V_{IH} = 1.8 \text{ V}, V_{IL} = 0 \text{ V}$ (Note	1.8	1.5	
Quiet output minimum dynamic V _{OH}	V _{OHV}	$V_{IH} = 2.5 \text{ V}, V_{IL} = 0 \text{ V}$ (Note) 2.5	1.9	V
		$V_{IH} = 3.3 \text{ V}, V_{IL} = 0 \text{ V}$ (Note) 3.3	2.2	

Note: This parameter is guaranteed by design.

Capacitive Characteristics (Ta = 25°C)

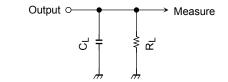
Characteristics	Symbol	Test Condition		V _{CC} (V)	Тур.	Unit
Input capacitance	C _{IN}	_		1.8, 2.5, 3.3	6	pF
Power dissipation capacitance	C _{PD}	f _{IN} = 10 MHz	(Note)	1.8, 2.5, 3.3	20	pF

Note: CPD is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$

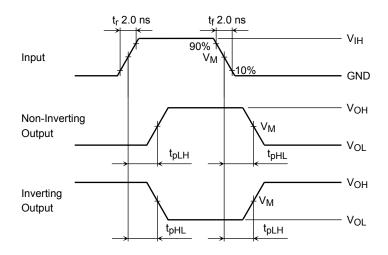
AC Test Circuit



	Vcc				
Symbol	$\begin{array}{c} 3.3 \pm 0.3 \text{ V} \\ 2.5 \pm 0.2 \text{ V} \\ 1.8 \pm 0.15 \text{ V} \end{array}$	1.5 ± 0.1 V 1.2V			
R_L	500 Ω	2 kΩ			
CL	30 pF	15 pF			

Figure 1

AC Waveform



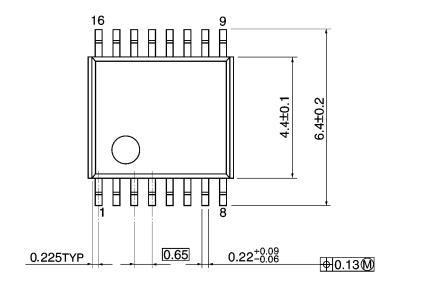
Symbol	Vcc				
	$3.3\pm0.3~\textrm{V}$	$2.5\pm0.2\textrm{V}$	1.8 ± 0.15 V	$1.5\pm0.1\textrm{V}$	1.2 V
V _{IH}	2.7 V	V _{CC}	V _{CC}	V _{CC}	V _{CC}
V _M	1.5 V	V _{CC} /2	V _{CC} /2	V _{CC} /2	V _{CC} /2

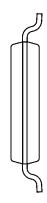
Figure 2 t_{pLH}, t_{pHL}

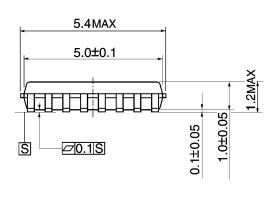
Package Dimensions

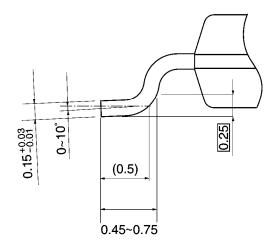
TSSOP16-P-0044-0.65A

Unit: mm





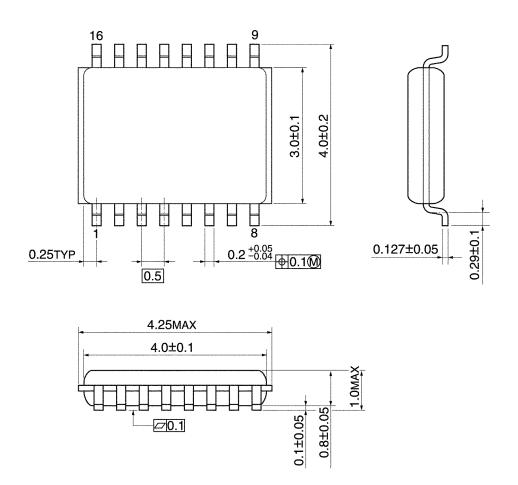




Weight: 0.06 g (typ.)

Package Dimensions

VSSOP16-P-0030-0.50 Unit: mm



Weight: 0.02 g (typ.)

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